

HA-2600/883 HA-2602/883

Wideband, High Impedance Operational Amplifiers

July 1994

Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- High Input Impedance (HA-2600/883). . . . 100M Ω (Min)
500M Ω (Typ)
- High Slew Rate. 4V/ μ s (Min)
7V/ μ s (Typ)
- Low Input Bias Current (HA-2600/883). . . . 10nA (Max)
1nA (Typ)
- Low Input Offset Current (HA-2600/883) . . . 4mV (Max)
- Wide Unity Gain Bandwidth 12MHz (Typ)
- Output Short Circuit Protection

Applications

- Video Amplifier
- Pulse Amplifier
- High-Q Active Filters
- High Speed Comparators
- Low Distortion Oscillators

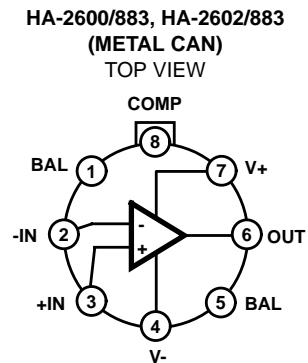
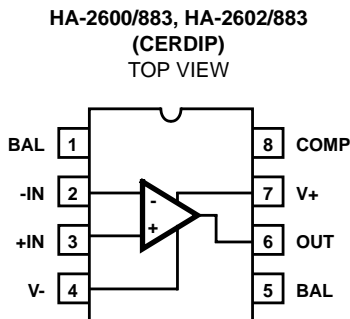
Description

HA-2600/883 and HA-2602/883 are internally compensated bipolar operational amplifiers that feature very high input impedance coupled with wideband AC performance. The high resistance of the input stage is complemented by low offset voltage (4mV max at +25°C for HA-2600/883) and low bias and offset current (10nA max at +25°C for HA-2600/883) to facilitate accurate signal processing. Offset voltage can be reduced further by means of an external nulling potentiometer. The 4V/ μ s minimum slew rate at +25°C and the minimum open loop gain of 100kV/V at +25°C enables the HA-2600/883 to perform high gain amplification of fast, wideband signals. These dynamic characteristics, coupled with fast settling times, make these amplifiers ideally suited to pulse amplification designs as well as high frequency or video applications. The frequency response of the amplifier can be tailored to exact design requirements by means of an external bandwidth control capacitor. Other high performance designs such as high gain, low distortion audio amplifiers, high-Q and wideband active filters and high speed comparators, are excellent uses of this part.

Ordering Information

PART NUMBER	TEMPERATURE RANGE	PACKAGE
HA2-2600/883	-55°C to +125°C	8 Pin Can
HA7-2600/883	-55°C to +125°C	8 Lead CerDIP
HA2-2602/883	-55°C to +125°C	8 Pin Can
HA7-2602/883	-55°C to +125°C	8 Lead CerDIP

Pinouts



Specifications HA-2600/883, HA-2602/883

Absolute Maximum Ratings

Voltage Between V+ and V- Terminals	40V
Differential Input Voltage	12V
Voltage at Either Input Terminal	V+ to V-
Peak Output Current	Full Short Circuit Protection
Junction Temperature (T _J)	+175°C
Storage Temperature Range	-65°C to +150°C
ESD Rating	<2000V
Lead Temperature (Soldering 10s)	+300°C

Thermal Information

Thermal Resistance	θ_{JA}	θ_{JC}
CerDIP Package	115°C/W	28°C/W
Metal Can Package	160°C/W	75°C/W
Package Power Dissipation Limit at +75°C for T _J ≤ +175°C		
CerDIP Package	870mW	
Metal Can Package	625mW	
Package Power Dissipation Derating Factor Above +75°C		
CerDIP Package	8.7mW/°C	
Metal Can Package	6.3mW/°C	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Operating Conditions

Operating Temperature Range	-55°C to +125°C	$V_{INCM} \leq 1/2 (V+ - V-)$
Operating Supply Voltage	±15V	$R_L \geq 2k\Omega$

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: V_{SUPPLY} = ±15V, R_{SOURCE} = 100Ω, R_{LOAD} = 500kΩ, V_{OUT} = 0V, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2600/883		HA-2602/883		UNITS
					MIN	MAX	MIN	MAX	
Input Offset Voltage	V _{IO}	V _{CM} = 0V	1	+25°C	-4	4	-5	5	mV
			2, 3	+125°C, -55°C	-6	6	-7	7	mV
Input Bias Current	+I _B	V _{CM} = 0V, +R _S = 100kΩ, -R _S = 100kΩ	1	+25°C	-10	10	-25	25	nA
			2, 3	+125°C, -55°C	-30	30	-60	60	nA
	-I _B	V _{CM} = 0V, +R _S = 100kΩ, -R _S = 100kΩ	1	+25°C	-10	10	-25	25	nA
			2, 3	+125°C, -55°C	-30	30	-60	60	nA
Input Offset Current	I _{IO}	V _{CM} = 0V, +R _S = 100kΩ, -R _S = 100kΩ	1	+25°C	-10	10	-25	25	nA
			2, 3	+125°C, -55°C	-30	30	-60	60	nA
Common Mode Range	+CMR	V+ = +4V, V- = -26V	1	+25°C	11	-	11	-	V
			2, 3	+125°C, -55°C	11	-	11	-	V
	-CMR	V+ = +26V, V- = -4V	1	+25°C	-	-11	-	-11	V
			2, 3	+125°C, -55°C	-	-11	-	-11	V
Large Signal Voltage Gain	+A _{VOL}	V _{OUT} = 0V and +10V, R _L = 2kΩ	4	+25°C	100	-	80	-	kV/V
			5, 6	+125°C, -55°C	70	-	60	-	kV/V
	-A _{VOL}	V _{OUT} = 0V and -10V, R _L = 2kΩ	4	+25°C	100	-	80	-	kV/V
			5, 6	+125°C, -55°C	70	-	60	-	kV/V
Common Mode Rejection Ratio	+CMRR	ΔV _{CM} = +10V, V+ = +5V, V- = -25V, V _{OUT} = -10V	1	+25°C	80	-	74	-	dB
			2, 3	+125°C, -55°C	80	-	74	-	dB
	-CMRR	ΔV _{CM} = -10V, V+ = +25V, V- = -5V, V _{OUT} = +10V	1	+25°C	80	-	74	-	dB
			2, 3	+125°C, -55°C	80	-	74	-	dB
Output Voltage Swing	+V _{OUT}	R _L = 2kΩ	4	+25°C	10	-	10	-	V
			5, 6	+125°C, -55°C	10	-	10	-	V
	-V _{OUT}	R _L = 2kΩ	4	+25°C	-	-10	-	-10	V
			5, 6	+125°C, -55°C	-	-10	-	-10	V

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TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

Device Tested at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 100\Omega$, $R_{LOAD} = 500k\Omega$, $V_{OUT} = 0V$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2600/883		HA-2602/883		UNITS
					MIN	MAX	MIN	MAX	
Output Current	+I _{OUT}	V _{OUT} = -10V	4	+25°C	15	-	10	-	mA
			5, 6	+125°C, -55°C	10	-	7.5	-	mA
	-I _{OUT}	V _{OUT} = +10V	4	+25°C	-	-15	-	-10	mA
			5, 6	+125°C, -55°C	-	-10	-	-7.5	mA
Quiescent Power Supply Current	+I _{CC}	V _{OUT} = 0V, I _{OUT} = 0mA	1	+25°C	-	3.7	-	3.7	mA
			2, 3	+125°C, -55°C	-	4.0	-	4.0	mA
	-I _{CC}	V _{OUT} = 0V, I _{OUT} = 0mA	1	+25°C	-3.7	-	-3.7	-	mA
			2, 3	+125°C, -55°C	-4.0	-	-4.0	-	mA
Power Supply Rejection Ratio	+PSRR	$\Delta V_{SUP} = \pm 5V$, V ₊ = +10V, V ₋ = -15V, V ₊ = +20V, V ₋ = -15V	1	+25°C	80	-	74	-	dB
			2, 3	+125°C, -55°C	80	-	74	-	dB
	-PSRR	$\Delta V_{SUP} = \pm 5V$, V ₊ = +15V, V ₋ = -10V, V ₊ = +15V, V ₋ = -20V	1	+25°C	80	-	74	-	dB
			2, 3	+125°C, -55°C	80	-	74	-	dB
Offset Voltage Adjustment	+V _{IOAdj}	Note 1	1	+25°C	V _{IO-1}	-	V _{IO-1}	-	mV
			2, 3	+125°C, -55°C	V _{IO-1}	-	V _{IO-1}	-	mV
	-V _{IOAdj}	Note 1	1	+25°C	V _{IO+1}	-	V _{IO+1}	-	mV
			2, 3	+125°C, -55°C	V _{IO+1}	-	V _{IO+1}	-	mV

NOTE:

- Offset adjustment range is [V_{IO}(Measured) ±1mV] minimum referred to output. This test is for functionality only to assure adjustment through 0V.

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at: $V_{SUPPLY} = \pm 15V$, $R_{SOURCE} = 50\Omega$, $R_{LOAD} = 2k\Omega$, $C_{LOAD} = 50pF$, $A_{VCL} = +1V/V$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	GROUP A SUBGROUPS	TEMPERATURE	HA-2600/883		HA-2602/883		UNITS
					MIN	MAX	MIN	MAX	
Slew Rate	+SR	V _{OUT} = -5V to +5V	7	+25°C	4	-	4	-	V/μs
			8A, 8B	+125°C, -55°C	3	-	3	-	V/μs
	-SR	V _{OUT} = +5V to -5V	7	+25°C	4	-	4	-	V/μs
			8A, 8B	+125°C, -55°C	3	-	3	-	V/μs
Rise and Fall Time	T _R	V _{OUT} = 0 to +200mV 10% ≤ T _R ≤ 90%	7	+25°C	-	60	-	60	ns
			8A, 8B	+125°C, -55°C	-	70	-	70	ns
	T _F	V _{OUT} = 0 to -200mV 10% ≤ T _F ≤ 90%	7	+25°C	-	60	-	60	ns
			8A, 8B	+125°C, -55°C	-	70	-	70	ns
Overshoot	+OS	V _{OUT} = 0 to +200mV	7	+25°C	-	40	-	40	%
			8A, 8B	+125°C, -55°C	-	50	-	50	%
	-OS	V _{OUT} = 0 to -200mV	7	+25°C	-	40	-	40	%
			8A, 8B	+125°C, -55°C	-	50	-	50	%

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TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Characterized at: $V_{SUPPLY} = \pm 15V$, $R_{LOAD} = 2k\Omega$, $C_{LOAD} = 50pF$, Unless Otherwise Specified.

PARAMETERS	SYMBOL	CONDITIONS	NOTES	TEMPERATURE	HA-2600/883		HA-2602/883		UNITS
					MIN	MAX	MIN	MAX	
Differential Input Resistance	R_{IN}	$V_{CM} = 0V$	1	+25°C	100	-	40	-	MΩ
Full Power Bandwidth	FPBW	$V_{PEAK} = 10V$	1, 2	+25°C	50	-	50	-	kHz
Minimum Closed Loop Stable Gain	CLSG	$R_L = 2k\Omega$, $C_L = 50pF$	1	-55°C to +125°C	1	-	1	-	V/V
Output Short Circuit Current	+ISC	$V_{OUT} = 1V$, $R_L = 10\Omega$	1	+25°C	-	50	-	50	mA
			1	+125°C	-	45	-	45	mA
			1	-55°C	-	60	-	60	mA
	-ISC	$V_{OUT} = -1V$, $R_L = 10\Omega$	1	+25°C	-50	-	-50	-	mA
			1	+125°C	-45	-	-45	-	mA
			1	-55°C	-60	-	-60	-	mA
Quiescent Power Consumption	PC	$V_{OUT} = 0V$, $I_{OUT} = 0mA$	1, 3	-55°C to +125°C	-	120	-	120	mW

NOTES:

- Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.
- Full Power Bandwidth guarantee based on Slew Rate measurement using $FPBW = \text{Slew Rate} / (2\pi V_{PEAK})$.
- Quiescent Power Consumption based upon Quiescent Supply Current test maximum. (No load on outputs.)

TABLE 4. ELECTRICAL TEST REQUIREMENTS

MIL-STD-883 TEST REQUIREMENTS	SUBGROUPS (SEE TABLES 1 AND 2)
Interim Electrical Parameters (Pre Burn-In)	1
Final Electrical Test Parameters	1 (Note 1), 2, 3, 4, 5, 6, 7, 8A, 8B
Group A Test Requirements	1, 2, 3, 4, 5, 6, 7, 8A, 8B
Groups C and D Endpoints	1

NOTE:

- PDA applies to Subgroup 1 only.

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Die Characteristics

DIE DIMENSIONS:

69 x 56 x 19 mils \pm 1 mils
1750 x 1420 x 483 μ m \pm 25.4 μ m

METALLIZATION:

Type: Al, 1% Cu
Thickness: 16k \AA \pm 2k \AA

GLASSIVATION:

Type: Nitride (Si₃N₄) over Silox (SiO₂, 5% Phos.)
Silox Thickness: 12k \AA \pm 2k \AA
Nitride Thickness: 3.5k \AA \pm 1.5k \AA

WORST CASE CURRENT DENSITY:

3.9 x 10⁴A/cm²

SUBSTRATE POTENTIAL (Powered Up): Unbiased

TRANSISTOR COUNT:

HA-2600/883: 140
HA-2602/883: 140

PROCESS: Bipolar Dielectric Isolation

Metallization Mask Layout

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